

ON Semiconductor

Is Now

onsemi™

To learn more about onsemi™, please visit our website at
www.onsemi.com

onsemi and **onsemi** and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi** product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner. Other names and brands may be claimed as the property of others.



ON Semiconductor®

KA5x02xx-SERIES

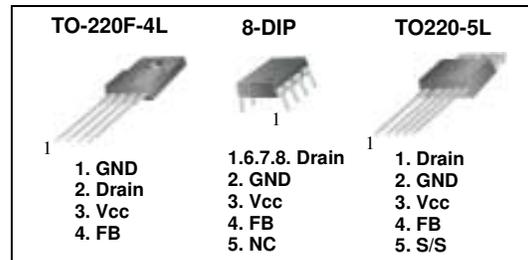
KA5H0265RC, KA5M0265R, KA5L0265R, KA5H02659RN/KA5M02659RN, KA5H0280R, KA5M0280R Power Switch

Features

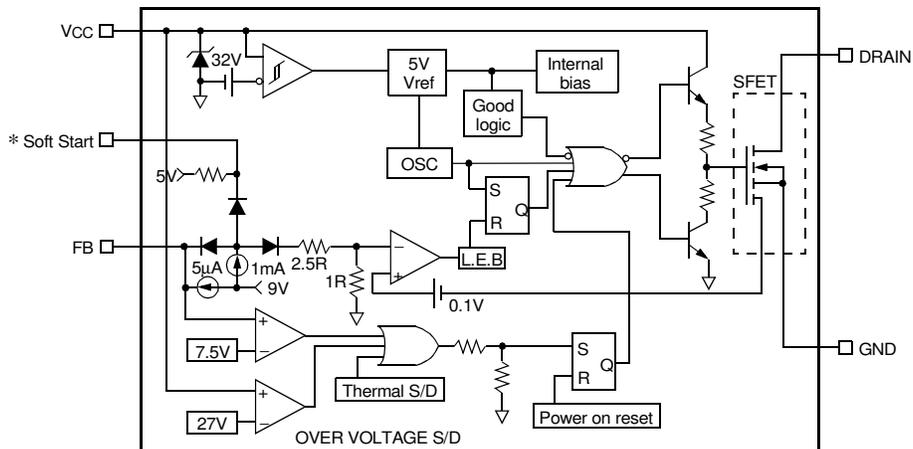
- Precision Fixed Operating Frequency (100/67/50kHz)
- Low Start-up Current (Typ. 100uA)
- Pulse by Pulse Current Limiting
- Over Load Protection
- Over Voltage Protection (Min. 25V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto-Restart Mode

Description

The Power Switch product family is specially designed for an off-line SMPS with minimal external components. The Power Switch consist of high voltage power SenseFET and current mode PWM IC. Included PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, and temperature compensated precision current sources for loop compensation and fault protection circuitry-compared to discrete MOSFET and controller or RCC switching converter solution. The Power Switch can reduce total component count, design size, weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for cost-effective design in either a flyback converter or a forward converter.



Internal Block Diagram



* KA5H0265RC

Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Characteristic	Symbol	Value	Unit
KA5x0265xRx			
Drain-Gate Voltage (RGS=1MΩ)	VDGR	650	V
Gate-Source (GND) Voltage	VGS	±30	V
Drain Current Pulsed ⁽¹⁾	IDM	8.0	ADC
Continuous Drain Current (TC=25°C)	ID	2.0	ADC
Continuous Drain Current (TC=100°C)	ID	1.3	ADC
Single Pulsed Avalanche Energy ⁽²⁾	EAS	68	mJ
Maximum Supply Voltage	VCC,MAX	30	V
Analog Input Voltage Range	VFB	-0.3 to VSD	V
Total Power Dissipation	PD	42	W
	Darting	0.33	W/°C
Operating Junction Temperature.	TJ	+160	°C
Operating Ambient Temperature.	TA	-25 to +85	°C
Storage Temperature Range.	TSTG	-55 to +150	°C
KA5x0280R			
Drain-Gate Voltage (RGS=1MΩ)	VDGR	800	V
Gate-Source (GND) Voltage	VGS	±30	V
Drain Current Pulsed ⁽¹⁾	IDM	8.0	ADC
Continuous Drain Current (TC=25°C)	ID	2.0	ADC
Continuous Drain Current (TC=100°C)	ID	1.3	ADC
Single Pulsed Avalanche Energy ⁽²⁾	EAS	90	mJ
Maximum Supply Voltage	VCC,MAX	30	V
Analog Input Voltage Range	VFB	-0.3 to VSD	V
Total Power Dissipation	PD	35	W
	Darting	0.28	W/°C
Operating Junction Temperature.	TJ	+160	°C
Operating Ambient Temperature.	TA	-25 to +85	°C
Storage Temperature Range.	TSTG	-55 to +150	°C

Note:

1. Repetitive rating: Pulse width limited by maximum junction temperature
2. L = 51mH, starting Tj = 25°C

Electrical Characteristics (SFET Part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
KA5x0265xRx						
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50μA	650	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=Max. Rating, VGS=0V	-	-	50	μA
		VDS=0.8Max. Rating, VGS=0V, TC=125°C	-	-	200	μA
Static Drain-Source on Resistance ^(Note)	RDS(ON)	VGS=10V, ID=0.5A	-	5.0	6.0	Ω
Forward Transconductance ^(Note)	gfs	VDS=50V, ID=0.5A	1.5	2.5	-	S
Input Capacitance	Ciss	VGS=0V, VDS=25V, f=1MHz	-	550	-	pF
Output Capacitance	Coss		-	38	-	
Reverse Transfer Capacitance	Crss		-	17	-	
Turn on Delay Time	td(on)	VDD=0.5B VDSS, ID=1.0A (MOSFET switching time is essentially independent of operating temperature)	-	20	-	nS
Rise Time	tr		-	15	-	
Turn Off Delay Time	td(off)		-	55	-	
Fall Time	tf		-	25	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	VGS=10V, ID=1.0A, VDS=0.5B VDSS (MOSFET switching time is essentially independent of operating temperature)	-	-	35	nC
Gate-Source Charge	Qgs		-	3	-	
Gate-Drain (Miller) Charge	Qgd		-	12	-	
KA5x0280R						
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50μA	800	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=Max. Rating, VGS=0V	-	-	50	μA
		VDS=0.8Max. Rating, VGS=0V, TC=125°C	-	-	200	μA
Static Drain-Source on Resistance ^(Note)	RDS(ON)	VGS=10V, ID=0.5A	-	5.6	7.0	Ω
Forward Transconductance ^(Note)	gfs	VDS=50V, ID=0.5A	1.5	2.5	-	S
Input Capacitance	Ciss	VGS=0V, VDS=25V, f=1MHz	-	250	-	pF
Output Capacitance	Coss		-	52	-	
Reverse Transfer Capacitance	Crss		-	25	-	
Turn on Delay Time	td(on)	VDD=0.5B VDSS, ID=1.0A (MOSFET switching time is essentially independent of operating temperature)	-	21	-	nS
Rise Time	tr		-	28	-	
Turn Off Delay Time	td(off)		-	77	-	
Fall Time	tf		-	24	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	VGS=10V, ID=1.0A, VDS=0.5B VDSS (MOSFET switching time is essentially independent of operating temperature)	-	-	60	nC
Gate-Source Charge	Qgs		-	15	-	
Gate-Drain (Miller) Charge	Qgd		-	20	-	

Note:

1. Pulse test: Pulse width ≤ 300μS, duty cycle ≤ 2%

$$2. S = \frac{1}{R}$$

Electrical Characteristics (Control Part) (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
UVLO SECTION						
Start Threshold Voltage	VSTART	VFB=GND	14	15	16	V
Stop Threshold Voltage	VSTOP	VFB=GND	8.2	8.8	9.4	V
OSCILLATOR SECTION						
Initial Accuracy	FOSC	KA5H0265xRx KA5H0280R	90	100	110	kHz
Initial Accuracy	FOSC	KA5M0265xRx KA5M0280R	61	67	73	kHz
Initial Accuracy	FOSC	KA5L0265R	45	50	55	kHz
Frequency Change With Temperature ⁽²⁾	$\Delta F/\Delta T$	-25°C ≤ Ta ≤ +85°C	-	±5	±10	%
Maximum Duty Cycle	Dmax	KA5H0265xRx KA5H0280R	62	67	72	%
Maximum Duty Cycle	Dmax	KA5M0265xRx KA5M0280R KA5L0265R	72	77	82	%
FEEDBACK SECTION						
Feedback Source Current	IFB	Ta=25°C, 0V ≤ Vfb ≤ 3V	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	VSD	Vfb ≤ 6.5V	6.9	7.5	8.1	V
Shutdown Delay Current	Idelay	Ta=25°C, 5V ≤ Vfb ≤ VSD	4	5	6	μA
SOFT START SECTION						
Soft Start Voltage	VSS	KA5H0265RC	4.7	5.0	5.3	V
Soft Start Current	ISS		0.8	1.0	1.2	mA
REFERENCE SECTION						
Output Voltage ⁽¹⁾	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability ⁽¹⁾⁽²⁾	Vref/ΔT	-25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C
CURRENT LIMIT(SELF-PROTECTION)SECTION						
Peak Current Limit	I _{OVER}	KA5x02659RN	0.79	0.9	1.01	A
Peak Current Limit	I _{OVER}	KA5x0265Rx KA5x0280R	1.05	1.2	1.34	A
PROTECTION SECTION						
Over Voltage Protection	VOVP	VCC ≥ 24V	25	27	29	V
Thermal Shutdown Temperature ⁽¹⁾	TSD	-	140	160	-	°C
TOTAL DEVICE SECTION						
Start-up Current	ISTART	VCC=14V	-	100	170	μA
Operating Supply Current (Control Part Only)	IOPR	VCC ≤ 28	-	7	12	mA

Note:

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process

Typical Performance Characteristics

(These characteristic graphs are normalized at Ta=25°C)

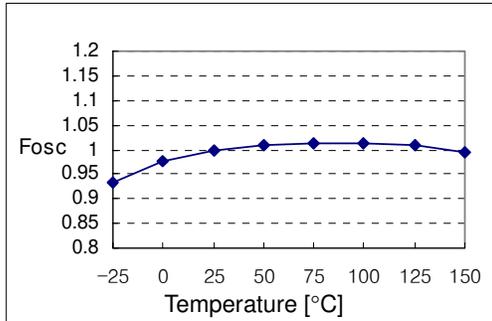


Figure 1. Operating Frequency

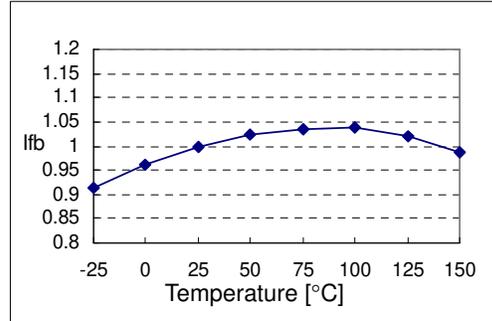


Figure 2. Feedback Source Current

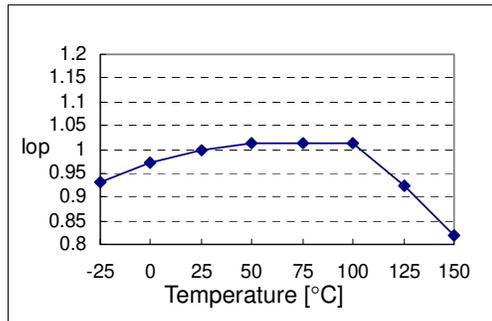


Figure 3. Operating Supply Current

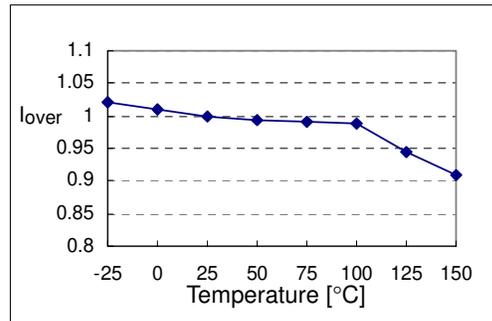


Figure 4. Peak Current Limit

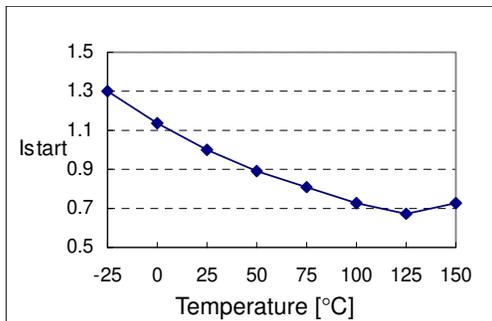


Figure 5. Start up Current

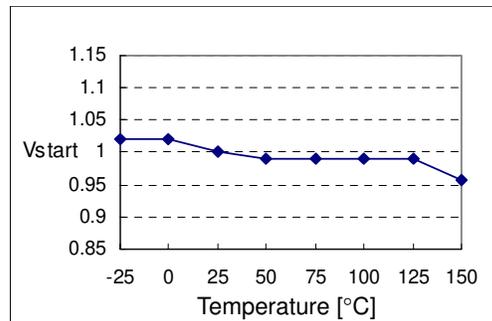


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at $T_a=25^\circ\text{C}$)

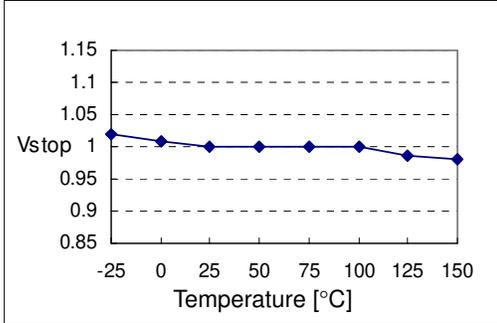


Figure 7. Stop Threshold Voltage

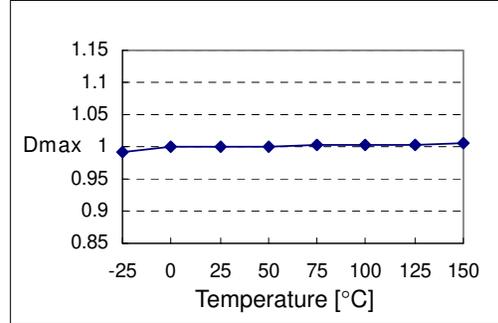


Figure 8. Maximum Duty Cycle

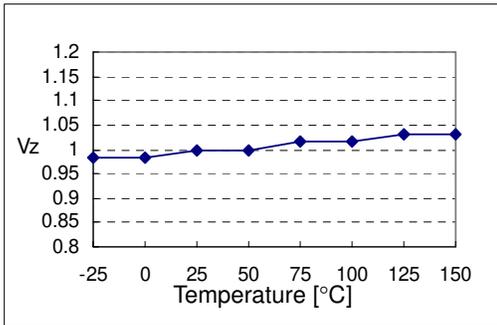


Figure 9. Vcc Zener Voltage

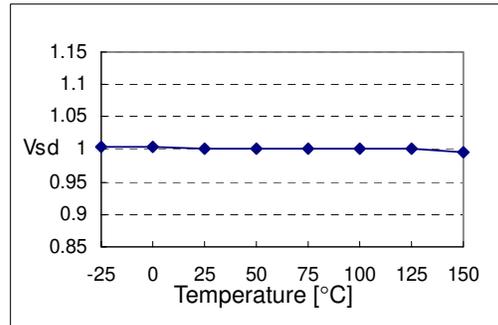


Figure 10. Shutdown Feedback Voltage

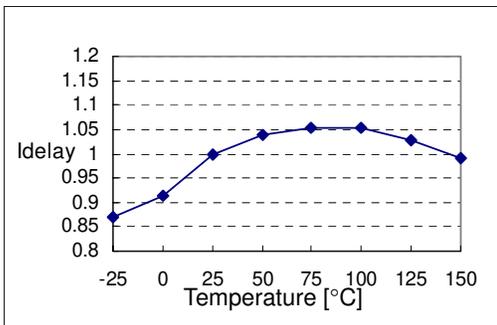


Figure 11. Shutdown Delay Current

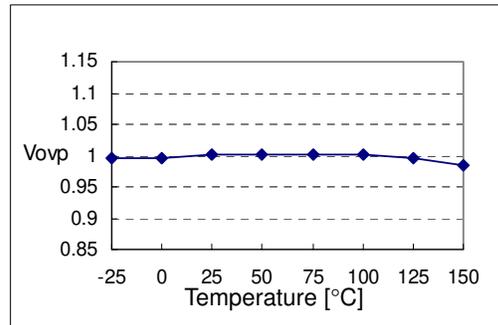


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at $T_a=25^\circ\text{C}$)

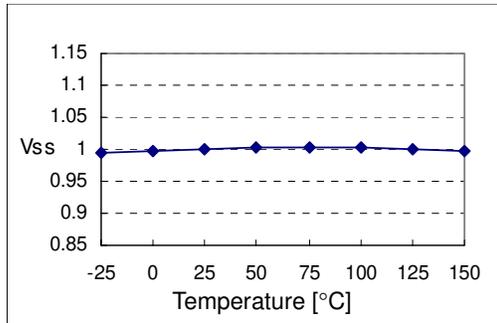


Figure13. Soft Start Voltage

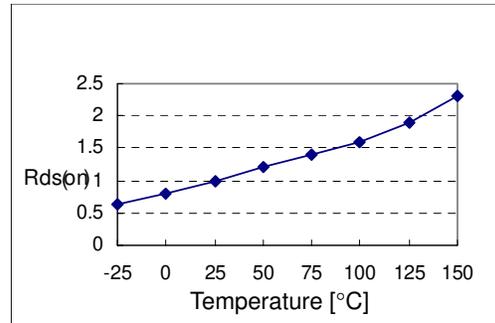
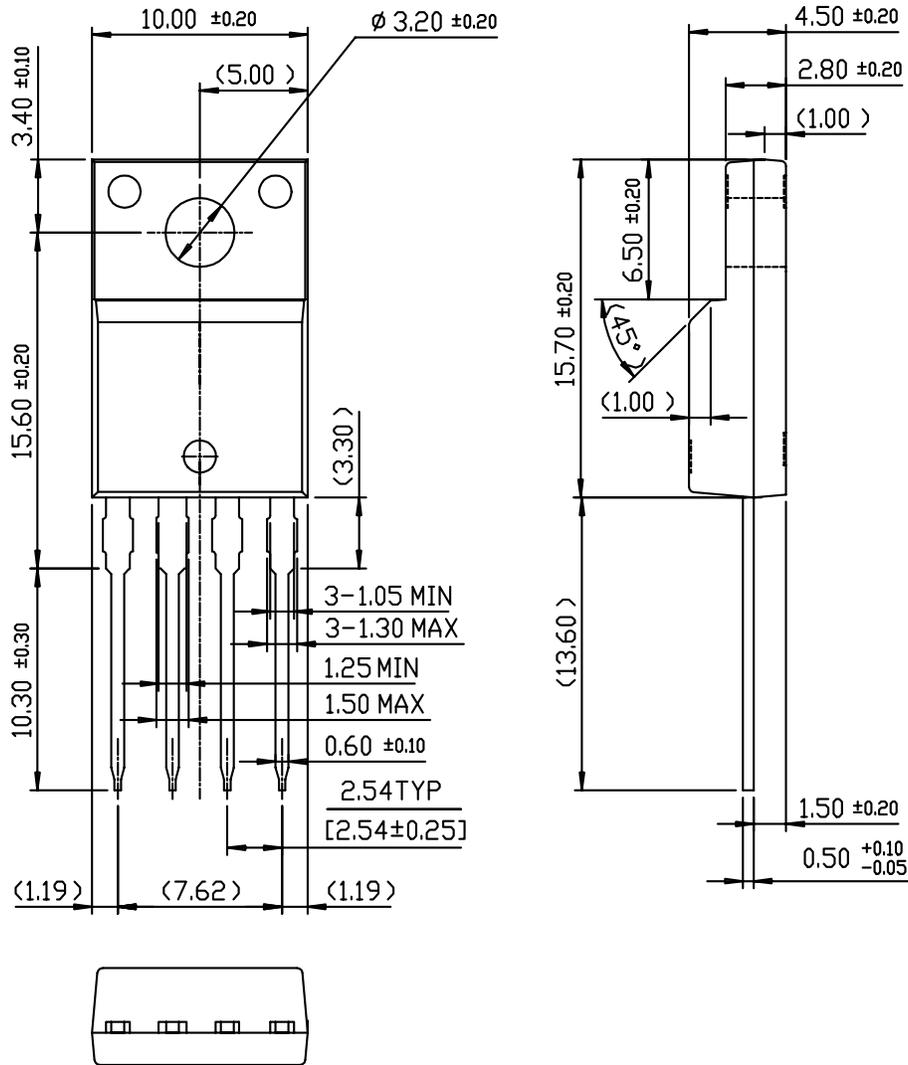


Figure 14. Static Drain-Source on Resistance

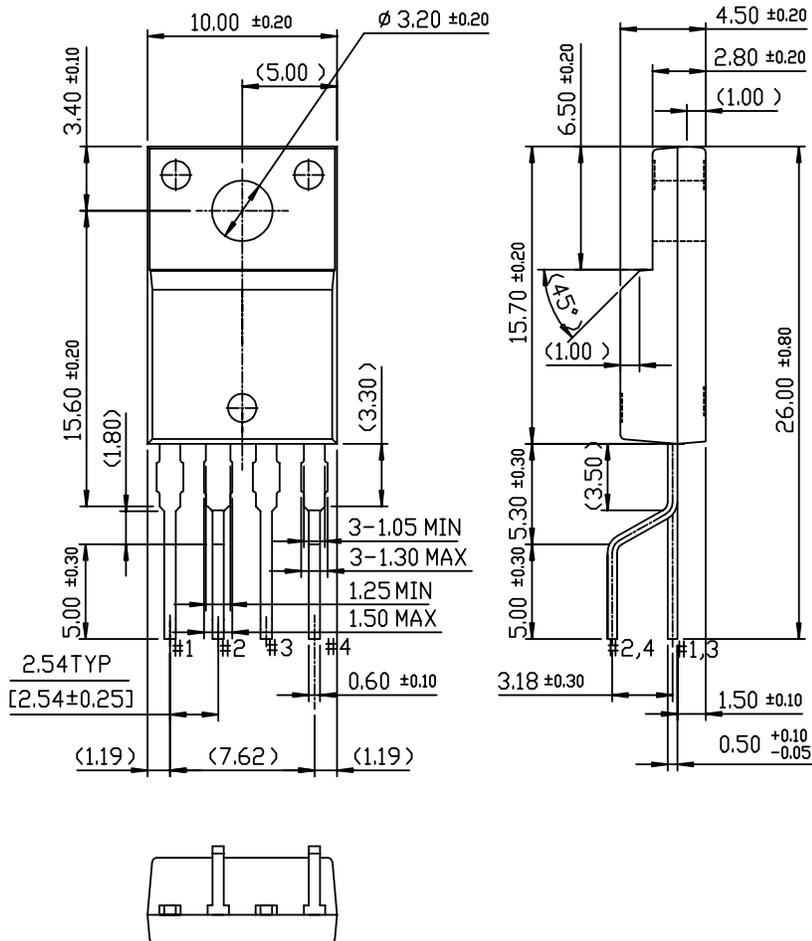
Package Dimensions

TO-220F-4L



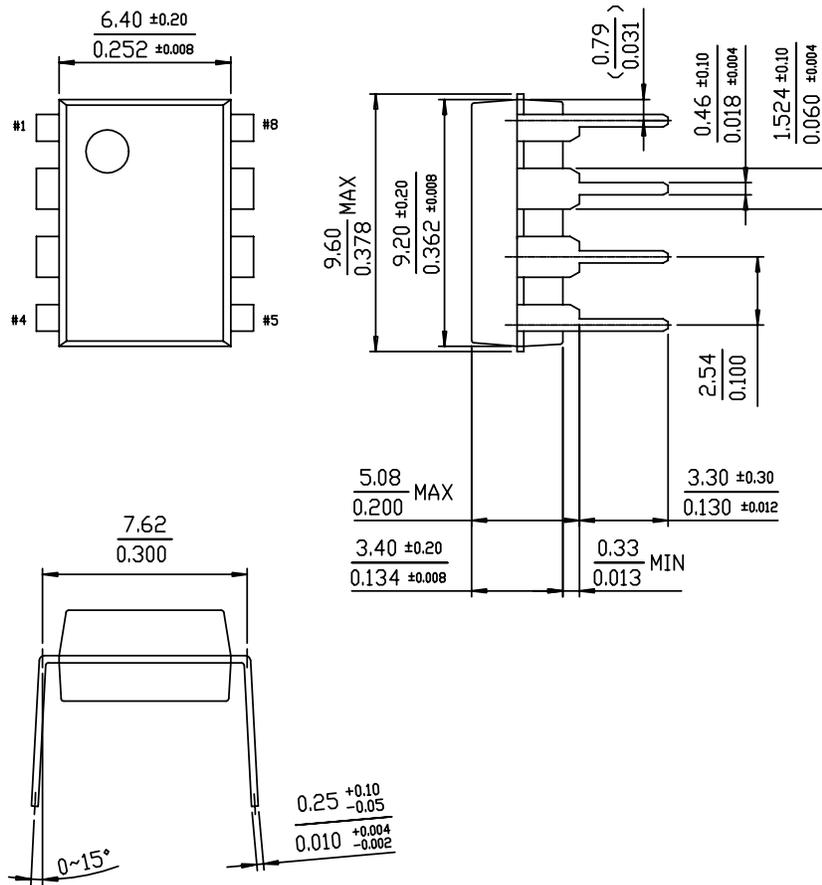
Package Dimensions (Continued)

TO-220F-4L(Forming)



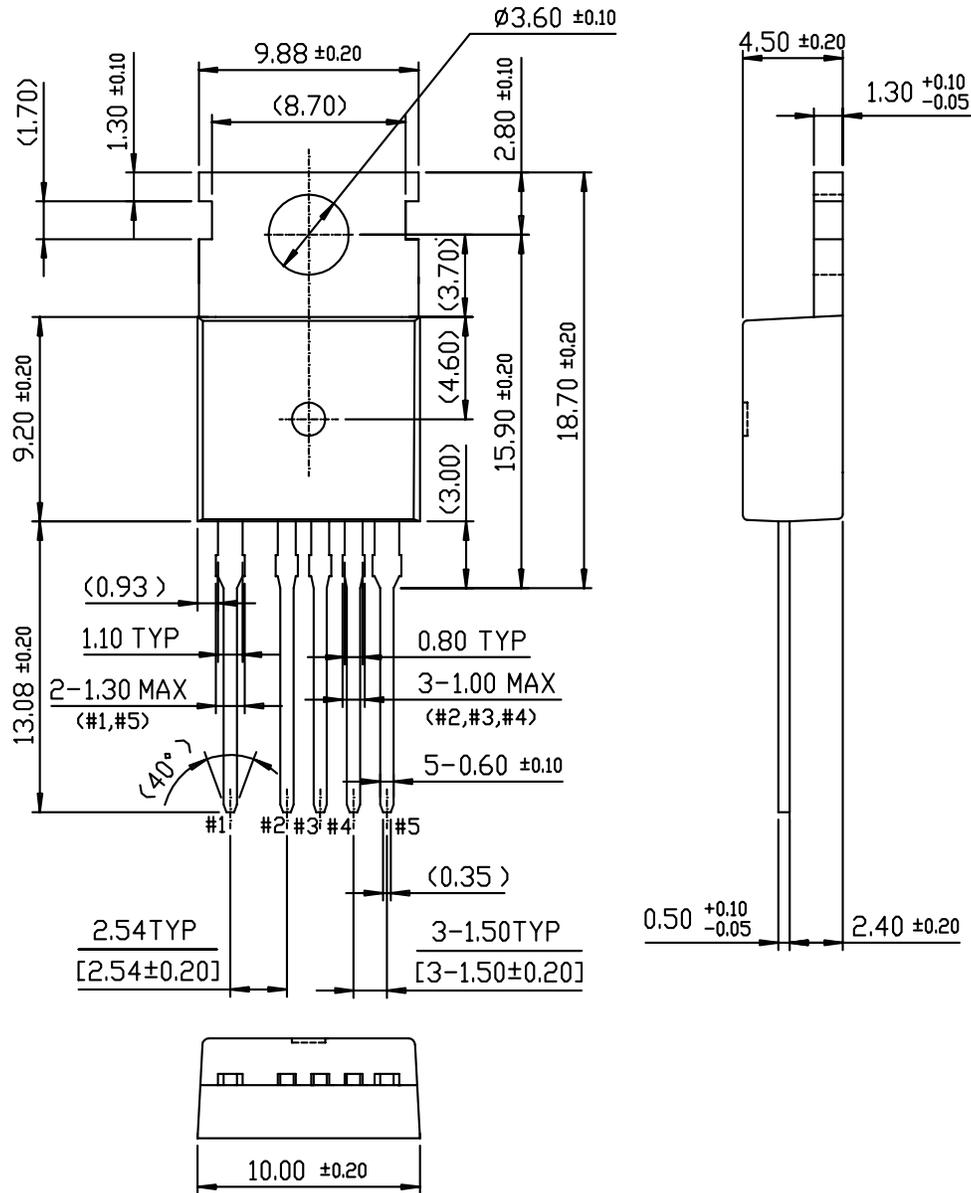
Package Dimensions (Continued)

8-DIP



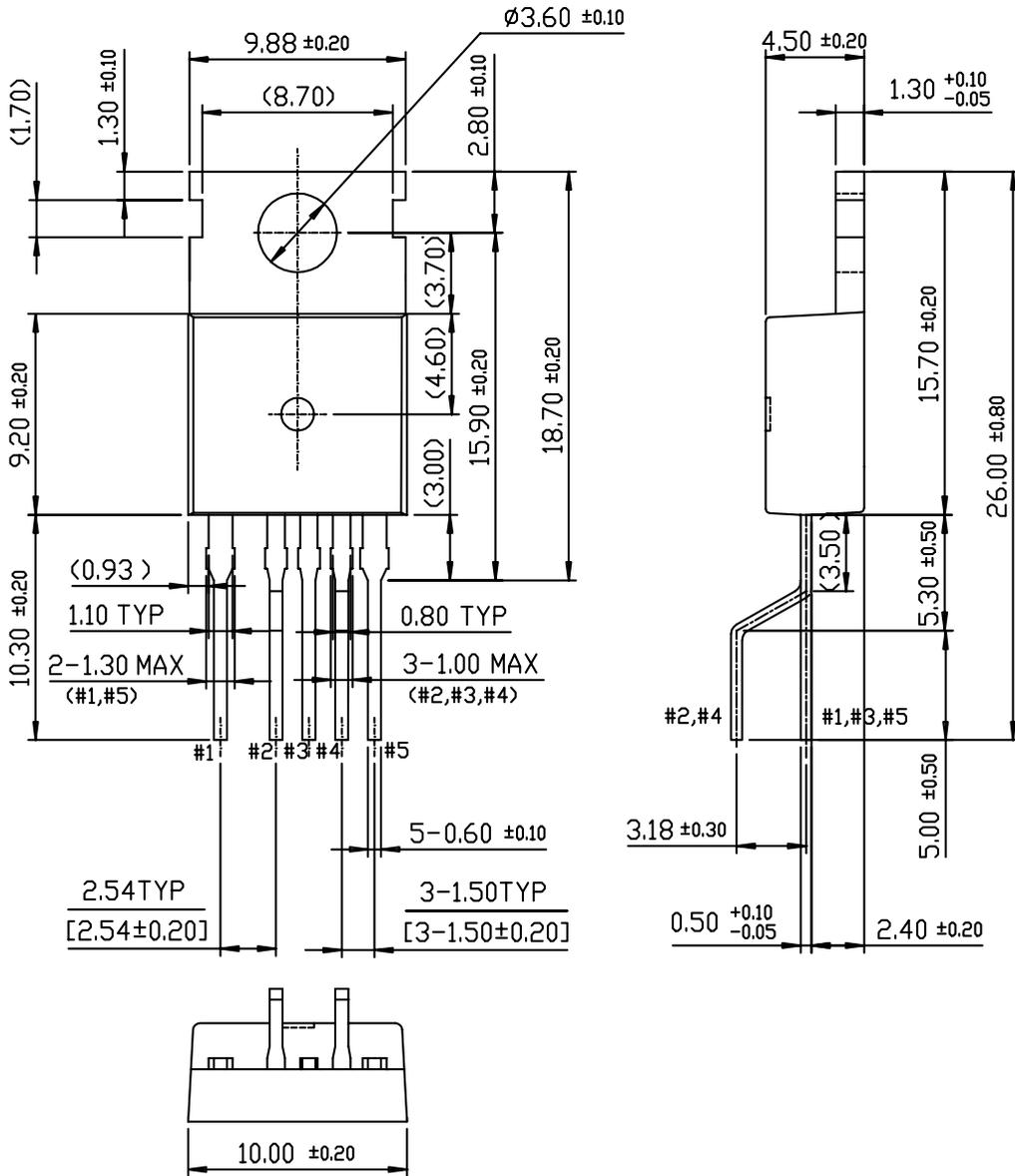
Package Dimensions (Continued)

TO-220-5L



Package Dimensions (Continued)

TO-220-5L(Forming)



Ordering Information

Product Number	Package	Marking Code	BVDSS	FOSC	RDS(on)
KA5H0265RCTU	TO-220-5L	5H0265RC	650V	100kHz	5Ω
KA5H0265RCYDTU	TO-220-5L(Forming)				
KA5M0265RTU	TO-220F-4L	5M0265R	650V	67kHz	5Ω
KA5M0265RYDTU	TO-220F-4L(Forming)				
KA5L0265RTU	TO-220F-4L	5L0265R	650V	50kHz	5Ω
KA5L0265RYDTU	TO-220F-4L(Forming)				
Product Number	Package	Marking Code	BVDSS	FOSC	RDS(on)
KA5H0280RTU	TO-220F-4L	5H0280R	800V	100kHz	5.6Ω
KA5H0280RYDTU	TO-220F-4L(Forming)				
KA5M0280RTU	TO-220F-4L	5M0280R	800V	67kHz	5.6Ω
KA5M0280RYDTU	TO-220F-4L(Forming)				
Product Number	Package	Marking Code	BVDSS	FOSC	RDS(on)
KA5H02659RN	8-DIP	5H02659R	650V	100kHz	5Ω
KA5M02659RN	8-DIP	5M02659R	650V	67kHz	5Ω

TU : Non Forming Type

YDTU : Forming Type

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com
Order Literature: <http://www.onsemi.com/orderlit>
For additional information, please contact your local
Sales Representative